TOSHIBA Bipolar Digital Integrated Circuit Silicon Monolithic

## ULN2803APG,ULN2803AFWG,ULN2804APG,ULN2804AFWG (Manufactured by Toshiba Malaysia)

#### 8ch Darlington Sink Driver

The ULN2803APG / AFWG Series are high-voltage, high-current darlington drivers comprised of eight NPN darlington pairs.

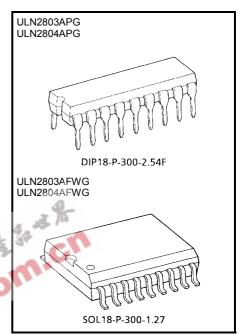
All units feature integral clamp diodes for switching inductive loads

Applications include relay, hammer, lamp and display (LED) drivers.

The suffix (G) appended to the part number represents a Lead (Pb)-Free product.

#### **Features**

- Output current (single output) 500 mA (Max.)
- High sustaining voltage output 50 V (Min.)
- Output clamp diodes
- Inputs compatible with various types of logic
- Package Type-APG : DIP-18pin
- Package Type-AFWG : SOL-18pin

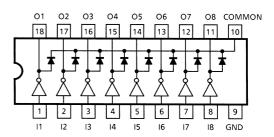


Weight

DIP18-P-300-2.54F: 1.478 g (Typ.) SOL18-P-300-1.27: 0.48 g (Typ.)

#### Pin Connection (top view)

Туре	Input Base Resistor	Designation
ULN2803APG / AFWG	2.7 kΩ	TTL, 5 V CMOS
ULN2804APG / AFWG	10.5 kΩ	6~15 V PMOS, CMOS



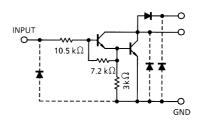
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### Schematics (each driver)

ULN2803APG / AFWG

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#### ULN2804APG / AFWG



Note: The input and output parasitic diodes cannot be used as clamp diodes.

## Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Output sustaining volt	age	V <sub>CE</sub> (SUS)	-0.5~50	V	
Output current		l <sub>OUT</sub>	500	mA / ch	
Input voltage		V <sub>IN</sub>	-0.5~30	٧	
Clamp diode reverse voltage		$V_{R}$	50	V	
Clamp diode forward current		I <sub>F</sub>	500	mΑ	
Power dissipation	APG	P <sub>D</sub>	1.47	W	
i ower dissipation	AFWG	10	0.92 / 1.31 (Note)		
Operating temperature		T <sub>opr</sub>	-40~85	°C	
Storage temperature		T <sub>stg</sub>	-55~150	°C	

Note: On Glass Epoxy PCB (75 × 114 × 1.6 mm Cu 20%)

## **TOSHIBA**

### Recommended Operating Conditions (Ta = -40~85°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Output sustaining voltage		V <sub>CE (SUS)</sub>		0	_	50	V	
	APG		T <sub>pw</sub> = 25 ms, Duty = 10%, 8 Circuits	0	_	347		
			T <sub>pw</sub> = 25 ms, Duty = 50%, 8 Circuits	0	_	123	mA /	
Output current		Гоит	T <sub>pw</sub> = 25 ms, Duty = 10%, 8 Circuits	0	_	268	ch	
	AFWG		T <sub>pw</sub> = 25 ms, Duty = 50%, 8 Circuits	0	_	90		
Input voltage	•	V <sub>IN</sub>		0	_	30	V	
Input voltage	ULN2803A	V		3.5	_	30	V	
(Output on)	ULN2804A	V <sub>IN</sub> (ON)		8	_	30	V	
Clamp diode reverse v	voltage	V <sub>R</sub>		_	_	50	V	
Clamp diode forward of	current	IF		_	_	400	mA	
Down discination	APG	Б	Ta = 85°C	_	_	0.76	W	
Power dissipation	AFWG	P <sub>D</sub>	Ta = 85°C (Note)	_	_	0.48		
Power dissipation   APG   AFWG   PD   Ta = 85°C   C   Note   -   -   0.76   W								

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## **TOSHIBA**

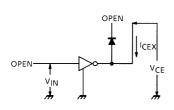
## **Electrical Characteristics (Ta = 25°C)**

Ch	naracteristic	Symbol	Test Cir- Cuit	Test C	ondition	Min	Тур.	Max	Unit
Output leakage current  ULN2804A		I <sub>CEX</sub>	1	V <sub>CE</sub> = 50 V	Ta = 25°C	1	_	50	μА
				V <sub>CE</sub> = 50 V	Ta = 85°C	1	_	100	
				V <sub>CE</sub> = 50 V	V <sub>IN</sub> = 1 V	_	_	500	
				I <sub>OUT</sub> = 350 mA,	I <sub>IN</sub> = 500 μA	1	1.3	1.6	
Collector-emit	ter saturation voltage	VCE (sat)	2	I <sub>OUT</sub> = 200 mA,	I <sub>OUT</sub> = 200 mA, I <sub>IN</sub> = 350 μA		1.1	1.3	V
				I <sub>OUT</sub> = 100 mA,	I <sub>IN</sub> = 250 μA	_	0.9	1.1	
	ULN2803A			V <sub>IN</sub> = 3.85 V			0.93	1.35	
Innut ourrent	LII NIGODAA	I <sub>IN (ON)</sub>	2	V <sub>IN</sub> = 5 V	= 5 V		0.35	0.5	mA
Input current	ULN2804A			V <sub>IN</sub> = 12 V	2 V		1.0	1.45	
		I <sub>IN (OFF)</sub>	4	I <sub>OUT</sub> = 500 μA, Ta = 85°C		50	65	_	μA
	ULN2803A	Vin (on)		V <sub>CE</sub> = 2 V, I <sub>OUT</sub> = 200 mA			_	2.4	V
			5	V <sub>CE</sub> = 2 V, I <sub>OUT</sub> = 250 mA V <sub>CE</sub> = 2 V, I <sub>OUT</sub> = 300 mA V <sub>CE</sub> = 2 V, I <sub>OUT</sub> = 125 mA V <sub>CE</sub> = 2 V, I <sub>OUT</sub> = 200 mA V <sub>CE</sub> = 2 V, I <sub>OUT</sub> = 275 mA V <sub>CE</sub> = 2 V, I <sub>OUT</sub> = 350 mA			_	2.7	
						_	_	3.0	
Input voltage (Output on)	ULN2804A					_	_	5.0	
(======================================						1	_	6.0	
						_	_	7.0	
							_	8.0	
DC current tra	nsfer ratio	h <sub>FE</sub>	2	V <sub>CE</sub> = 2 V, I <sub>OU7</sub>	T = 350 mA	1000	_	_	
Clamp diode reverse current		IR	6	<b>Ta</b> = 25°C	(Note)	_	_	50	μА
				Ta = 85°C	(Note)	_	_	100	
Clamp diode for	orward voltage	V <sub>F</sub>	7	I <sub>F</sub> = 350 mA		_	_	2.0	V
Input capacita	nce	C <sub>IN</sub>	_			_	15	_	pF
Turn-on delay		ton	0	R <sub>L</sub> = 125 Ω, V <sub>O</sub>	<sub>UT</sub> = 50 V	_	0.1	_	
Turn-off delay		toff	8	R <sub>L</sub> = 125 Ω, V <sub>O</sub>	UT = 50 V	- 0.2		_	μs –

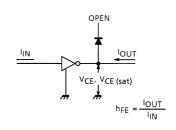
Note:  $V_R = V_R MAX$ .

## **Test Circuit**

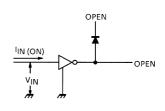
## 1. ICEX



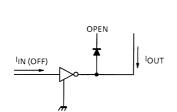
## 2. V<sub>CE (sat),</sub> h<sub>FE</sub>



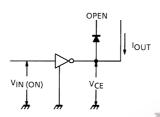
## 3. I<sub>IN (ON)</sub>



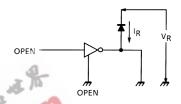
### 4. In (OFF)



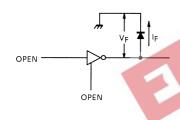
## 5. V<sub>IN (ON)</sub>



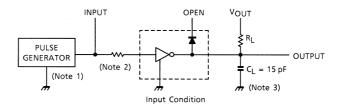
## 6. I<sub>R</sub>

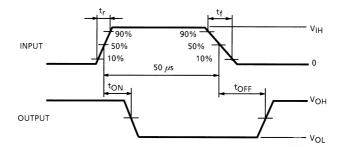


## 7. V<sub>F</sub>



#### 8. ton, toff





Note 1: Pulse Width 50 µs, Duty Cycle 10%

Note 2: See below.

		`		V <sub>OL</sub>
1:	Pulse Width 50 $\mu$ s, Duty Couput Impedance 50 $\Omega$ , t <sub>r</sub>		s	2 34 A
2:	See below.			2 19 6
	Input Condition		1 32	om.
	Type Number	R1	V <sub>IH</sub>	
	ULN2803A	0Ω	3 V	
	ULN2804A	Ω0	8 V	

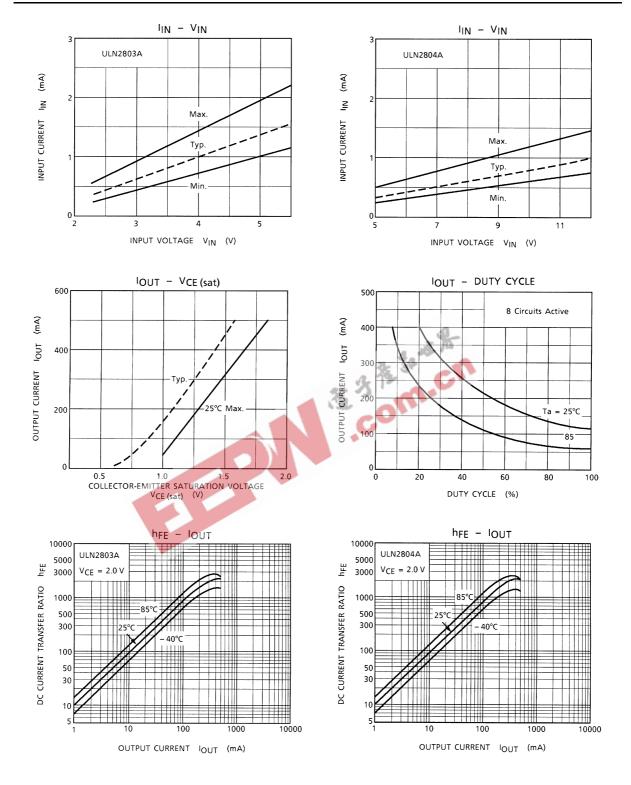
Note 3: CL includes probe and jig capacitance

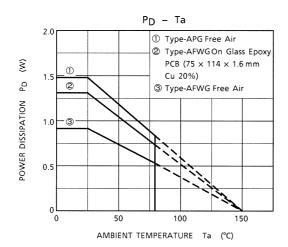
#### **Precautions for Using**

This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.

Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.

Utmost care is necessary in the design of the output line, COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

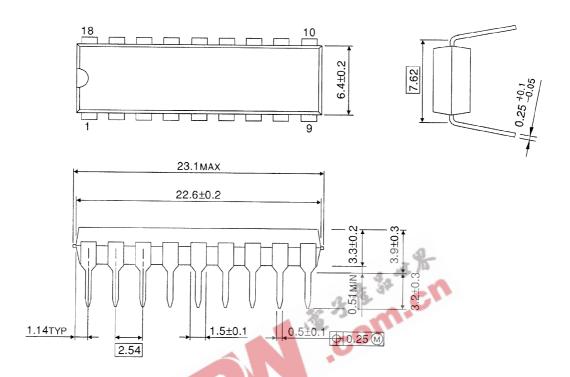






## **Package Dimensions**

DIP18-P-300-2.54F Unit: mm

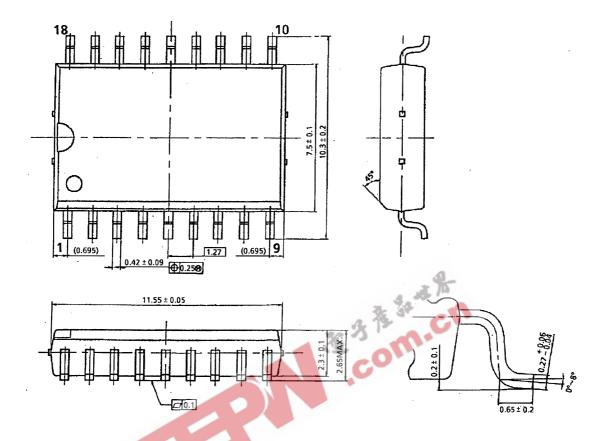


Weight: 1.478 g (Typ.)

## **Package Dimensions**

SOL18-P-300-1.27

Unit: mm



Weight: 0.48 g (Typ.)

#### **Notes on Contents**

#### 1. Schematics

The schematics may be simplified or some parts of them may be omitted for explanatory purposes.

#### 2. Absolute Maximum Ratings

The absolute maximum ratings of a semiconductor device are a set of specified parameter values that must not be exceeded during operation, even for an instant.

If any of these ratings are exceeded during operation, the electrical characteristics of the device may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed.

Moreover, any exceeding of the ratings during operation may cause breakdown, damage and/or degradation in other equipment. Applications using the device should be designed so that no absolute maximum rating will ever be exceeded under any operating conditions.

Before using, creating and/or producing designs, refer to and comply with the precautions and conditions set forth in this document.

#### 3. Recommended Operating Conditions

The values of the conditions are applied within the range of the operating temperature and not guaranteed.

#### 4. AC Characteristics

AC characteristics that mean turn-on and turn-off time are targeted design values and not guaranteed.

#### 5. Application Circuits

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially in the phase of mass production design.

In furnishing these examples of application circuits, Toshiba does not grant the use of any industrial property rights.

#### 6. Graphics Characteristics

Graphics characteristics are reference ones and not guaranteed.

#### Handling of the IC

Ensure that the product is installed correctly to prevent breakdown, damage and/or degradation in the product or equipment.

About solderability, following conditions were confirmed

- Solderability
  - (1) Use of Sn-37Pb solder Bath
    - · solder bath temperature = 230°C
    - · dipping time = 5 seconds
    - · the number of times = once
    - · use of R-type flux
  - (2) Use of Sn-3.0Ag-0.5Cu solder Bath
    - · solder bath temperature = 245°C
    - · dipping time = 5 seconds
    - · the number of times = once
    - · use of R-type flux

#### **RESTRICTIONS ON PRODUCT USE**

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  devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical
  stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety
  in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such
  TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  - In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc. 021023\_A
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